

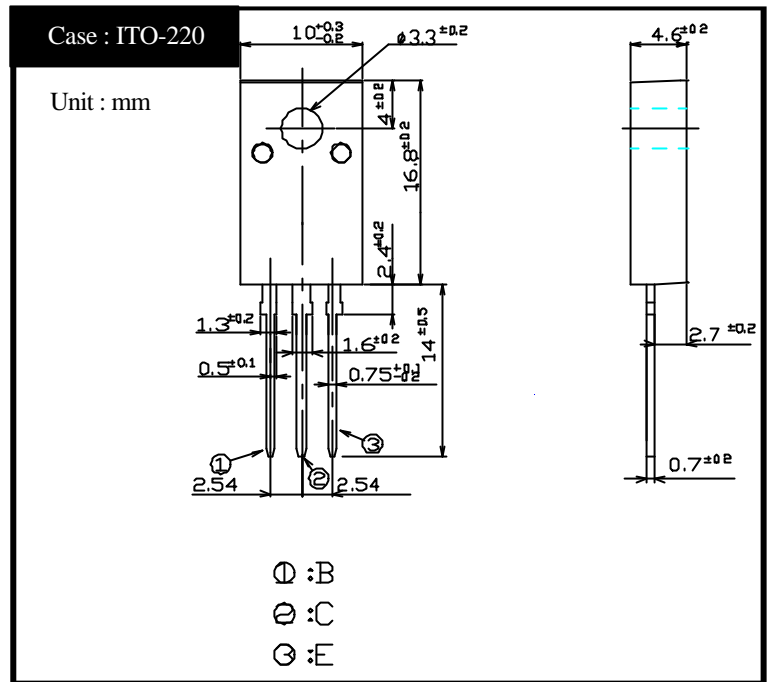
SHINDENGEN

Darlington Transistor

2SD1790
(TP4L6Z)

± 4A NPN

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings

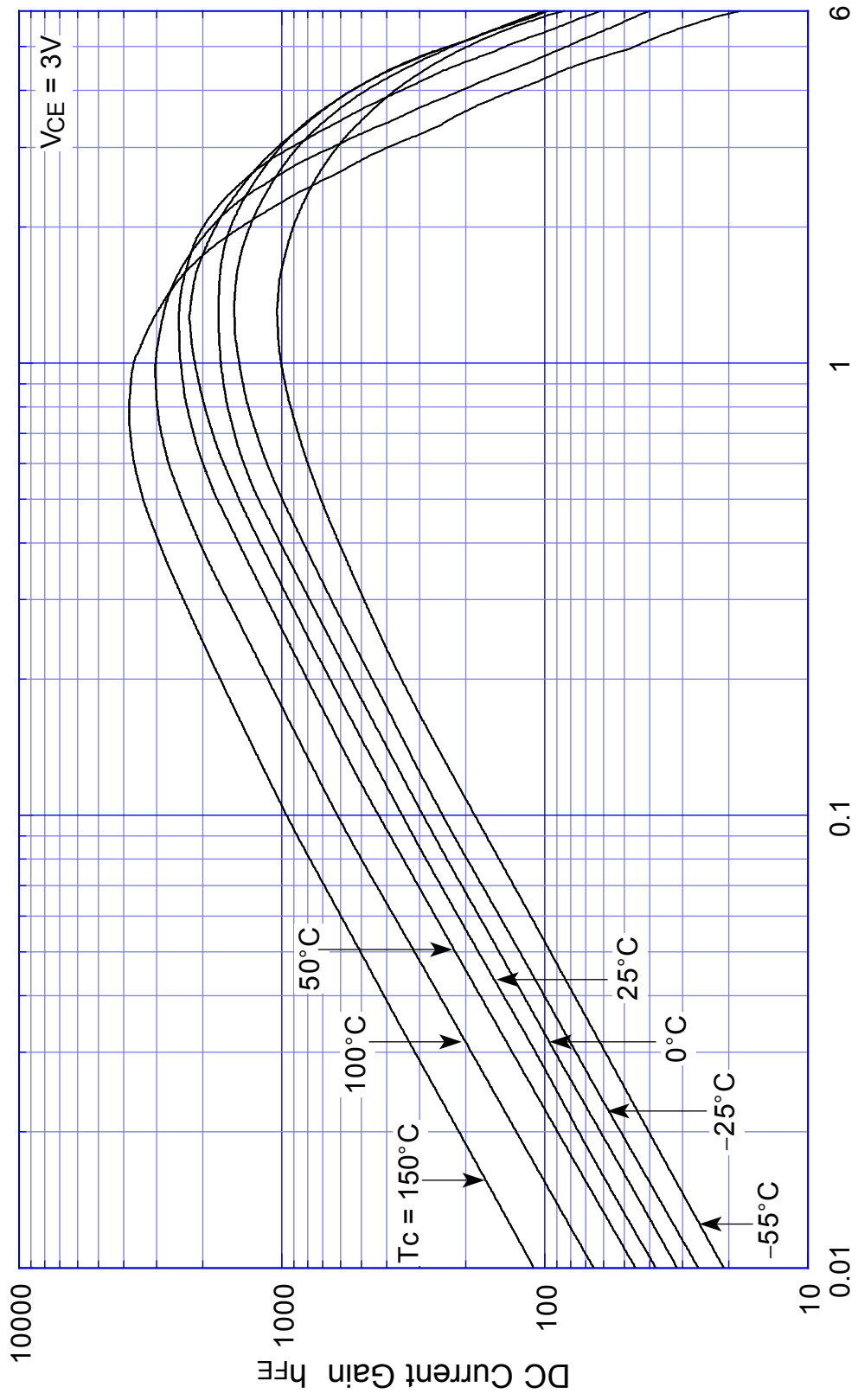
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55 ~ +150	
Junction Temperature	T _j		+150	
Collector to Base Voltage	V _{CBO}		60 ^{±10}	V
Collector to Emitter Voltage	V _{CEO}		60 ^{±10}	V
Emitter to Base Voltage	V _{EBO}		7	V
Collector Current DC	I _C		± 4	A
Collector Current Peak	I _{CP}		± 6	A
Base Current DC	I _B		0.3	A
Base Current Peak	I _{BP}		0.5	A
Total Transistor Dissipation	P _T	T _c = 25	25	W
Dielectric Strength	V _{dis}	Terminals to case AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

Electrical Characteristics (T_c=25)

Item	Symbol	Conditions	Ratings	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = 40V	Max 0.1	mA
	I _{CEO}	V _{CE} = 40V	Max 0.1	
Emitter Cutoff Current	I _{EBO}	V _{EB} = 7V	Max 5	mA
DC Current Gain	h _{FE}	V _{CE} = 3V, I _C = 1A	Min 1,500	
			Max 30,000	
Collector to Emitter Saturation Voltage	V _{CE(sat)}	I _C = 1A	Max 1.5	V
Base to Emitter Saturation Voltage	V _{BE(sat)}	I _B = 2mA	Max 2.0	V
Thermal Resistance	θ _{JC}	Junction to case	Max 5.0	/W
Transition Frequency	f _T	V _{CE} = 10V, I _C = 0.4A	TYP 20	MHz
Turn on Time	t _{on}		Max 2	μs
Storage Time	t _s	I _C = 1A I _{B1} = I _{B2} = 2mA R _L = 25	Max 12	
Fall Time	t _f	V _{BB2} = 4V	Max 5	

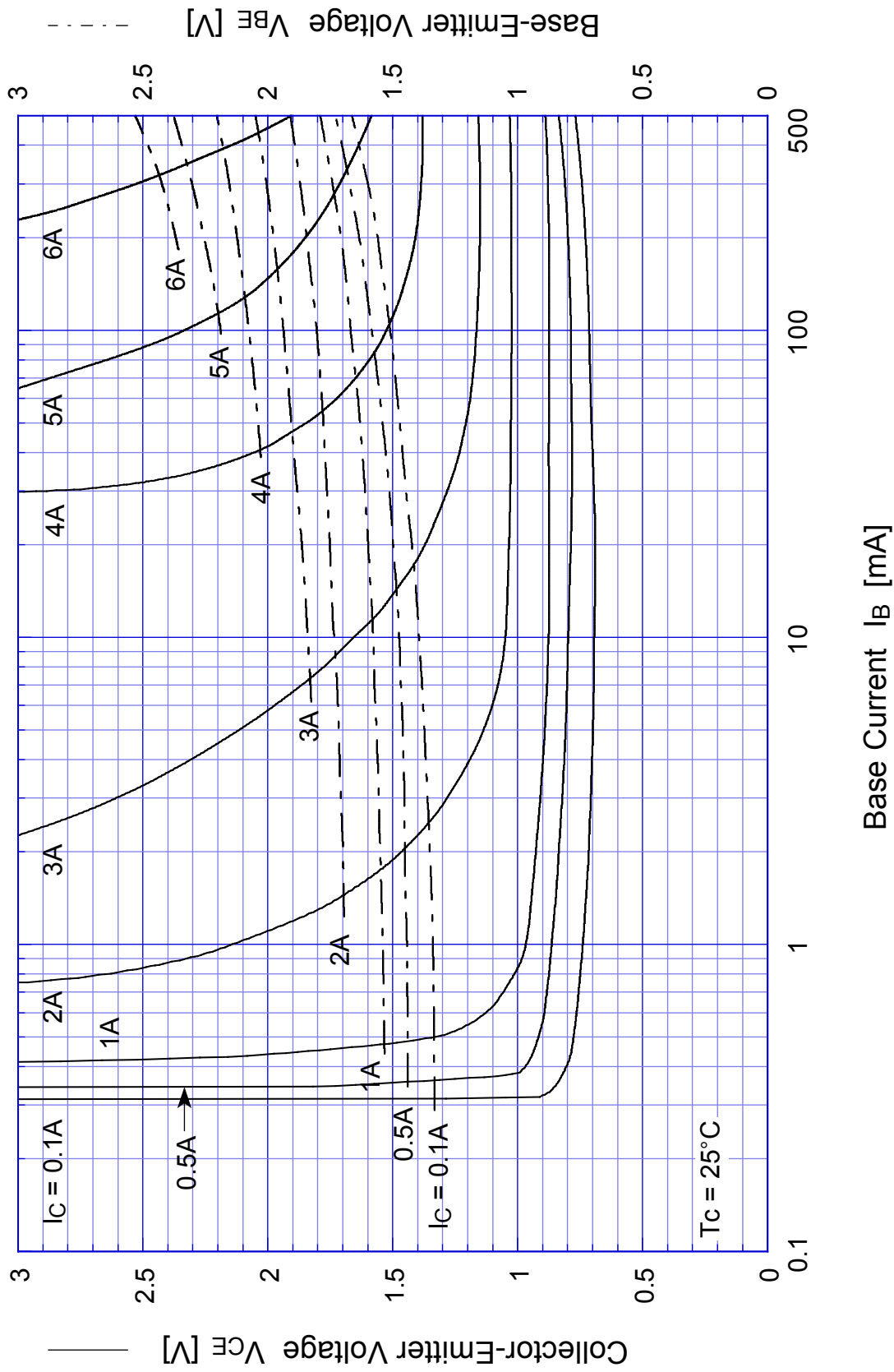
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$h_{FE} - I_c$



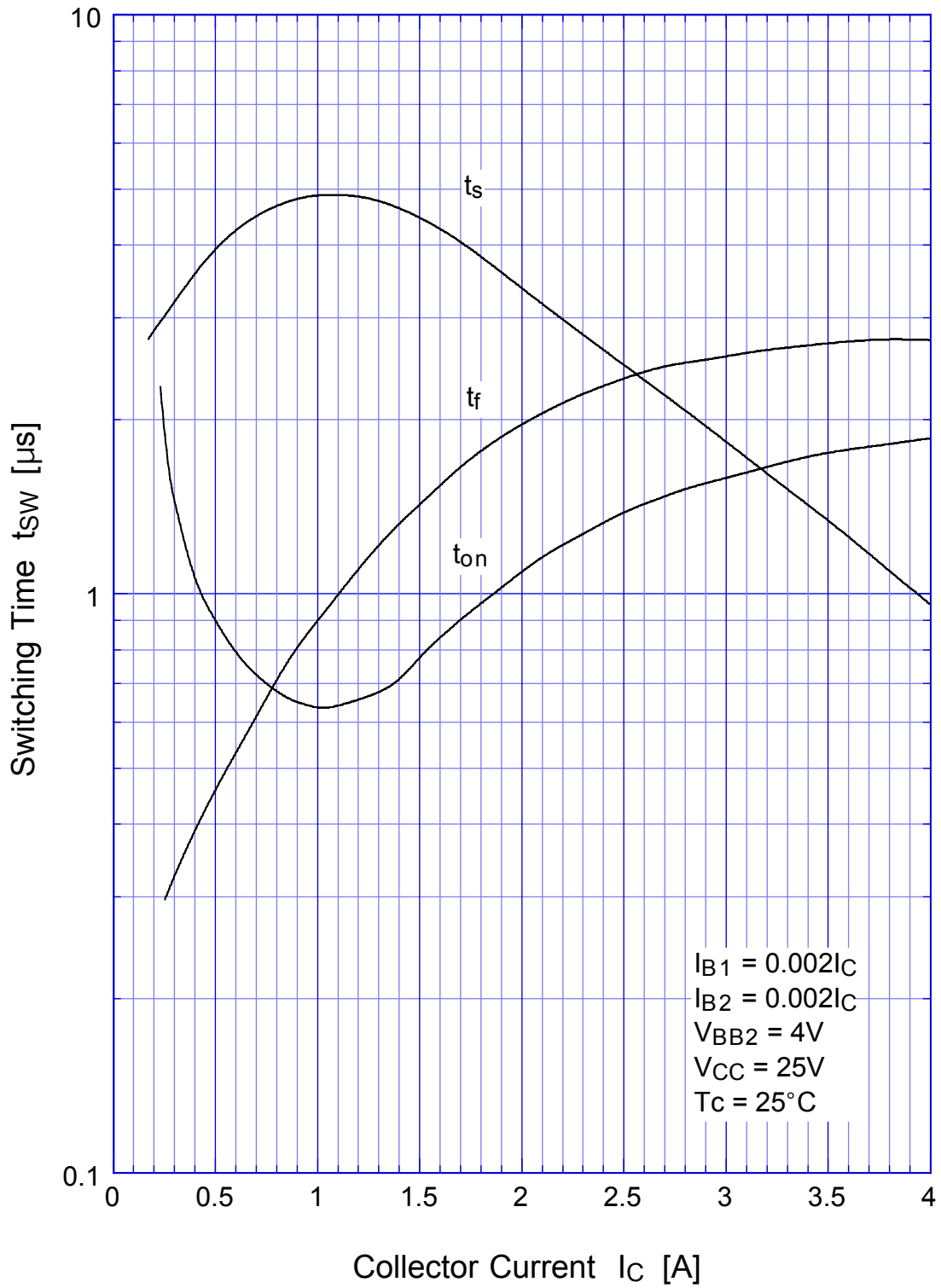
Collector Current I_c [A]

2SD1790 Saturation Voltage



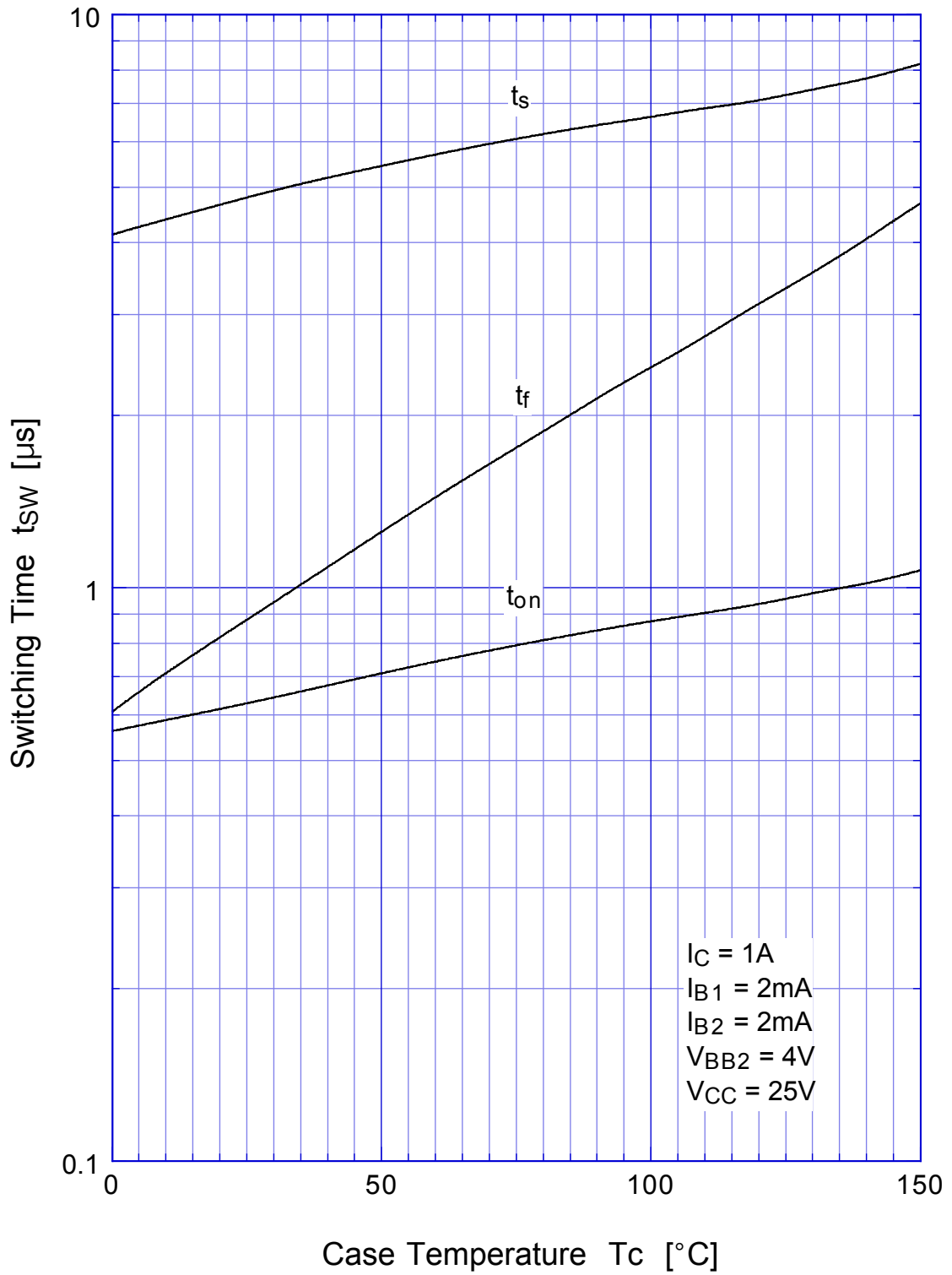
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Switching Time - I_C

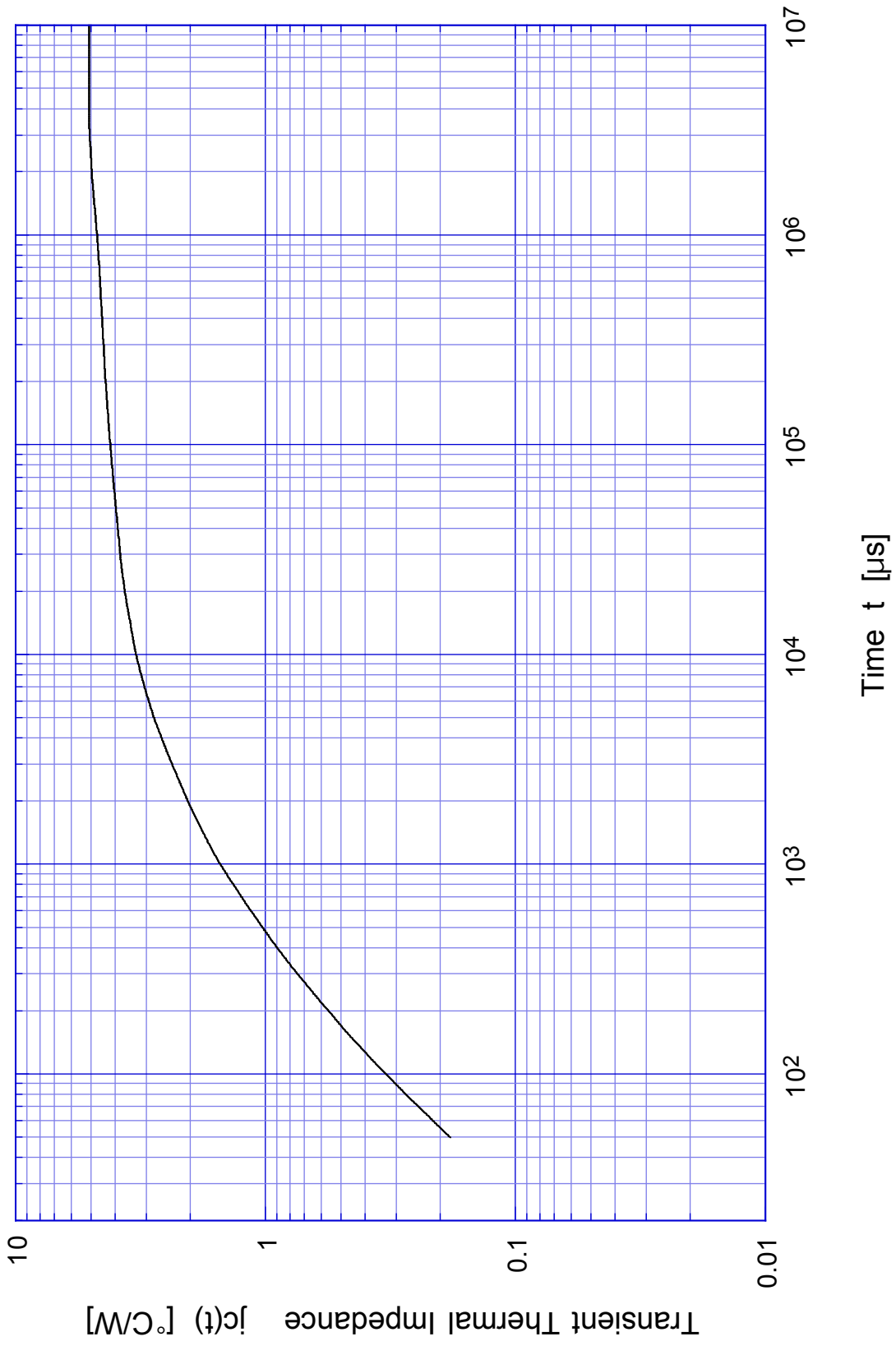


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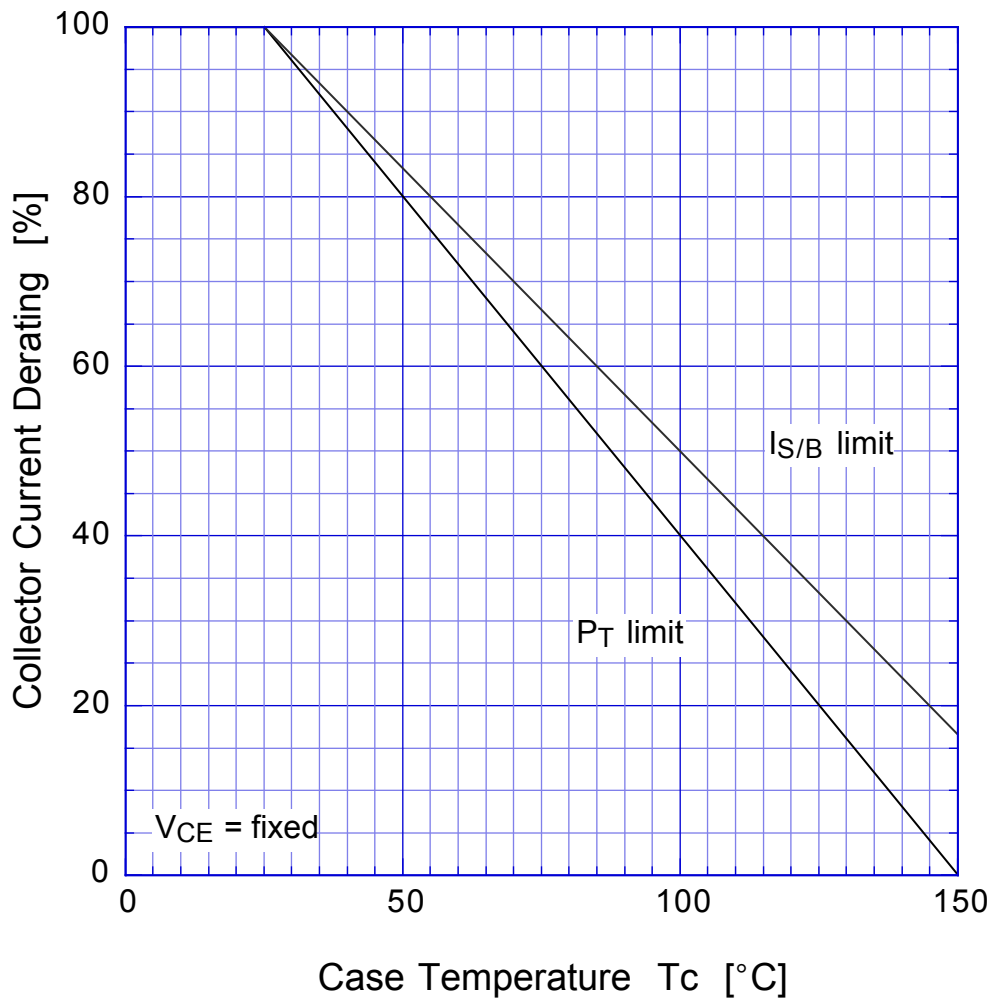
Switching Time - Tc



2SD1790 Transient Thermal Impedance



2SD1790 Collector Current Derating



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$V_{EC} - I_C$

